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- In case of amplitude modulation if three sine waves simultaneously modulate the carrier with individual modulation indices m_1 , m_2 and m_3 , then total modulation index is given by:
 - (A) $\sqrt{m_1^2 + m_2^2 + m_3^2}$
 - (B) $m_1 + m_2 + m_3$
 - (C) $\sqrt[3]{m_1 m_2 m_3}$
 - (D) $(m_1 + m_2 + m_3)/2$
- Identify the false statement with regard to advantages and disadvantages of FM:
 - (A) FM is, or can be made, relatively immune to the effects of noise
 - (B) A much smaller channel is required by FM, up to 1/10 times as small as that needed by AM
 - (C) FM transmitting and receiving equipments tend to be more complex
 - (D) The amplitude of the FM wave is constant. It is thus independent of modulation index
- 3. The absorption of radio waves by the atmosphere depends on :
 - (A) the distance from the transmitter
 - (B) the polarization of the wave
 - (C) the frequency of the wave
 - (D) both the distance and the polarization of the wave
- 4. The most suitable method out of the following in measurement of the resistance of expected value less than 1 Ω is:
 - (A) Limit bridge method
 - (B) Wheatstone's bridge method
 - (C) Loss of charge method
 - (D) Kelvin's bridge method

- The diffusion current density is :
 - (A) directly proportional to the concentration gradient of charge carriers
 - (B) inversely proportional to the concentration gradient of charge carriers
 - (C) independent of the concentration gradient of charge carriers
 - (D) directly proportional to concentration of charge carriers
- 6. With increase in temperature:
 - (A) the resistivity of a conductor decreases while that of a semiconductor increases
 - (B) the resistivity of both conductor and semicodnuctor increases
 - (C) the resistivity of both conductor and semiconductor decreases
 - (D) the resistivity of a conductor increases and that of semiconductor decreases
- 7. The ratio of electron and hole concentrations in case of an intrinsic semiconductor is:
 - (A) greater than one
 - (B) less than one
 - (C) equal to one
 - (D) equal to square of the intrinsic carrier concentration

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- 8. In case of a centre-tap full-wave rectifier if V_{max} is the peak voltage across the secondary of the transformer, the voltage appearing across the nonconducting diode is:
 - (A) V_{max}
 - (B) 2 V_{max}
 - (C) $\sqrt{2}V_{\text{max}}$
 - (D) $V_{max}/\sqrt{2}$
- 9. In common base configuration if I_E is the emitter current and α is the current gain, the part of the emitter current which forms the collector current is:
 - (A) αI_E
 - (B) $(1 \alpha)I_R$
 - (C) $(1 \alpha)I_E + \alpha$
 - (D) $(1 + \alpha)I_E$
- 10. The configuration having the highest input resistance, lowest output resistance and voltage gain less than unity is:
 - (A) CE
 - (B) CC
 - (C) CB
 - (D) Both CE and CB
- 11. The graph plotted between the drain current I_D and gate-source voltage V_{GS} for a given drain source voltage V_{DS} of a MOSFET is called its :
 - (A) output characteristics
 - (B) input characteristics
 - (C) transfer characteristics
 - (D) load line

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| 12. | 2. The process used in growing thin layers of the material on the semiconduct | | | | | | |
|--|---|--|--|--|--|--|--|
| | surface in fabrication of the semiconductor devices is known as: | | | | | | |
| | (A) | Lithography | | | | | |
| | (B) | Metallization | | | | | |
| | (C) | Diffusion | | | | | |
| | (D) | Epitaxy | | | | | |
| 13. | The | operation of N-channel JFET involves flow of : | | | | | |
| | (A) | electrons | | | | | |
| | (B) | holes | | | | | |
| | (C) | both electrons and holes | | | | | |
| | (D) | doping impurity ions | | | | | |
| 14. The principle of superposition is a fundamental consequence of : | | | | | | | |
| | (A) | non-linearity | | | | | |
| | (B) | linearity | | | | | |
| | (C) | reciprocity | | | | | |
| | (D) | both non-linearity and reciprocity | | | | | |
| 15. | The | branch relationship of a two terminal resistive element is linear if | | | | | |
| | it is | | | | | | |
| | (A) | homogeneous | | | | | |
| | (B) | additive | | | | | |
| | (C) | homogeneous and additive | | | | | |
| | (D) | none of the above | | | | | |
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| 16. | In n | model analysis of networks the choice of a reference node : | |
|---------|------------|---|---|
| | (A) | alters the currents flowing through its branches | |
| | (B) | effects the operation of the network | |
| | (C) | alters the voltage across the elements | |
| | (D) | affects the voltage of various nodes | |
| 17. | The | drain-source voltage at which the channel opening of a JFET reduce | 8 |
| | to ze | ero is known as : | |
| | (A) | cut-in voltage | |
| | (B) | punch-through voltage | |
| | (C) | pinch-off voltage | |
| | (D) | breakdown voltage | |
| 18. | The | quality factor of any circuit is given by : | |
| | (A) | 2π times the energy dissipated per cycle divided by the energy stored | d |
| | | per cycle | |
| | (B) | 2π times the energy stored per cycle divided by the energy dissipated | i |
| | | per cycle | |
| | (C) | 2π times the energy stored per cycle | |
| | (D) | 2π times the energy dissipated per cycle | |
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| | | 1.1.0 | |

| 19, | The | normal binary code of Gray 11011 is: | | | | |
|-----|---|--|--|--|--|--|
| | (A) | 11111 | | | | |
| | (B) | 11110 | | | | |
| | (C) | 11010 | | | | |
| | (D) | 10010 | | | | |
| 20. | At r | esonance frequency w, the Q of a series LCR circuit is given by: | | | | |
| | (A) | ωL/R | | | | |
| | (B) | ωC/R | | | | |
| | (C) | R/wL | | | | |
| | (D) | ω/RL | | | | |
| 21, | 1. A device said to be active if its I-V characteristic lies in the : | | | | | |
| | (A) | 1st quadrant | | | | |
| | (B) | 2nd and 4th quadrants | | | | |
| | (C) | 1st and 3rd quadrants | | | | |
| | (D) | 3rd quadrant | | | | |
| 22. | The | threshold voltage of p-channel enhancement MOSFET is : | | | | |
| | (A) | zero | | | | |
| | (B) | positive | | | | |
| | (C) | negative | | | | |
| | (D) | independent of device geometry | | | | |
| | | | | | | |

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| 28 | s^2 | $\frac{b}{+as+b}$ is a second order filter gain function that realizes the | | | | | | |
|-----|------------|---|--|--|--|--|--|--|
| | ch | aracteristics of a : | | | | | | |
| | (A) | band pass filter | | | | | | |
| | (B) | band reject filter | | | | | | |
| | (C) | | | | | | | |
| | (D) | low pass filter | | | | | | |
| 24. | Ide | Identify the false statement from the following. The RC filters offer: | | | | | | |
| | (A) | increased circuit reliability because for all the processing steps can be automated | | | | | | |
| | (B) | improvement in performance because high quality components can be realized | | | | | | |
| | (C) | an increase in parasitic | | | | | | |
| | (D) | simpler design process | | | | | | |
| 25. | The | The frequency response curve of a first order filter rolls-off at a rate of: | | | | | | |
| 2 | (A) | 10 db/decade | | | | | | |
| | (B) | 20 db/decade | | | | | | |
| | (C) | 10 db/octave | | | | | | |
| | (D) | 20 db/octave | | | | | | |
| 26. | The t | The total number of sets of input conditions that will produce a high output | | | | | | |
| | from | a three-input OR gate is : | | | | | | |
| | | 7 | | | | | | |
| | (B) | 8 | | | | | | |
| | (C) | 15 | | | | | | |
| | (D) | 16 | | | | | | |

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| 27. | The | e logic expression $\overline{\overline{A} + B} + \overline{\overline{A} + \overline{B}}$ on simplification reduces to : | | | | |
|---------|---|--|--|--|--|--|
| | (A) | A + B | | | | |
| | (B) | A | | | | |
| | (C) | AB | | | | |
| | (D) | В | | | | |
| 28. | A NAND gate with all inputs connected together will function as : | | | | | |
| | (A) | OR gate | | | | |
| | (B) | AND gate | | | | |
| | (C) | NOT gate | | | | |
| | (D) | NOR gate | | | | |
| 29. | According to De Morgan's theorem : | | | | | |
| | (A) | the complement of the product of two or more variables is equal to the | | | | |
| | | sum of the variables | | | | |
| | (B) | the complement of the product of two or more variables is equal to the | | | | |
| | | product of the variables | | | | |
| | (C) | the complement of the product of two or more variables is equal to the | | | | |
| | | product of the complements of the variables | | | | |
| | (D) | the complement of the product of two or more variables is equal to the | | | | |
| | | sum of the complements of the variables | | | | |
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| 30. | When | 2's complement of a binary number is taken twice, the result w | vill | | | | |
|---------|--|---|------|--|--|--|--|
| | be: | | | | | | |
| | (A) | square of the original number | | | | | |
| | (B) | double of the original number | | | | | |
| | (C) | original number | | | | | |
| | (D) | half of the original number | | | | | |
| 31. | When binary number 1110101 is divided by the number 1001, the result | | | | | | |
| | is : | | | | | | |
| | (A) | 1001 | | | | | |
| | (B) | 1101 | | | | | |
| | (C) | 1010 | | | | | |
| | (D) | 0101 | | | | | |
| 32. | In Sch | hottky TTL families a Schottky diode clamping between base and collec | tor | | | | |
| | of the | of the transistor is used to: | | | | | |
| | (A) | prevent transistor saturation | | | | | |
| | (B) | prevent transistor breakdown | | | | | |
| | (C) | prevent short circuit failure | | | | | |
| | (D) | increase the fan-in | | | | | |
| 33. | Identify the false statement. Excess-3 code : | | | | | | |
| | (A) | is an unweighted code | | | | | |
| | (B) | is used in representing a alphanumeric data | | | | | |
| | (C) | is a self-complementing code | | | | | |
| | (D) | uses only 10 of the 16 possible 4-bit code groups | | | | | |
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- 34. In logic circuits the positive logic is one in which :
 - (A) logic 0 and logic 1 are represented by negative and positive voltages respectively
 - (B) logic 0 and logic 1 are represented by zero and positive voltages respectively
 - (C) the voltage corresponding to logic 0 is lower than that corresponding to logic 1
 - (D) the voltage corresponding to logic 0 is higher than that corresponding to logic 1
- 35. With a NAND RS-latch a low R and low S produces:
 - (A) high output
 - (B) low output
 - (C) no change
 - (D) race condition
- 36. A multivibrator which continuously switches between two quasi-stable states without external excitation is known as:
 - (A) bistable multivibrator
 - (B) monostable multivibrator
 - (C) astable multivibrator
 - (D) flip-flop

| | 37. | The | logical value of the logical function A + A is: | |
|-----|---------|------------|---|--------|
| (SI | | (A) | 0 | |
| 82 | | (B) | 1 | |
| | | (C) | A | |
| | | (D) | Ā | × |
| | 38. | The | minimum number of JK flip-flops required for designing a modulu | us-10 |
| | | coun | ter is : | |
| | | (A) | 4 | |
| | | (B) | 6 | |
| | | (C) | 8 | |
| | | (D) | 10 | |
| | 39. | Iden | tify the correct statement from the following: | |
| | | (A) | Static RAM is volatile while dynamic RAM is non-volatile | |
| | | (B) | Static RAM is non-volatile while dynamic RAM is volatile | |
| | | (C) | Both static and dynamic RAM are volative | |
| | | (D) | Both static and dynamic RAM are non-volatile | |
| | 40. | Dyna | amic RAM : | |
| | | (A) | uses bipolar or MOS flip-flop | |
| | | (B) | uses MOSFET's and capacitors | |
| | | (C) | needs no refreshing of the data | |
| | | (D) | contains less memory cells than a static RAM on the same chip | area |
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| 41. | 8085 A microprocessor has: | | | | | | | |
|--------|--|---|--|--|--|--|--|--|
| | (A) | 10 restart instructions | | | | | | |
| | (B) | 8 restart instructions | | | | | | |
| | (C) | 6 restart instructions | | | | | | |
| | (D) | 4 restart instructions | | | | | | |
| 42. | The | The execution of RST2 instruction vectors to location: | | | | | | |
| | (A) | 0000 _H | | | | | | |
| | (B) | 0008 _H | | | | | | |
| * | (C) | 0010 _H | | | | | | |
| | (D) | 0018 _H | | | | | | |
| 43. | The | The hardware restart of 8085A microprocessor which has the highest priority | | | | | | |
| | and | when active branches the program to location 0024 _H is: | | | | | | |
| | (A) | RST 7.5 | | | | | | |
| | (B) | RST 6.5 | | | | | | |
| | (C) | RST 5.5 | | | | | | |
| | (D) | Trap | | | | | | |
| 44. | The decrease in gain of an RC coupled amplifier at low frequency is mainly | | | | | | | |
| | due to: | | | | | | | |
| | (A) | junction capacitances of the transistor | | | | | | |
| | (B) | emitter resistance | | | | | | |
| | (C) | coupling capacitor | | | | | | |
| | (D) | voltage divider resistances used for self-biasing of the amplifier | | | | | | |
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- 45. If R_i and R_o are the input and output resistances of an amplifier, its power gain in decibels equals its voltage gain in decibels when :
 - (A) $R_i = 2R_o$
 - (B) $R_i = R_o$
 - (C) $R_i = R_0/2$
 - (D) $R_i = 5R_o$
- 46. A phasor is :
 - (A) a vector representing the magnitude and phase of an alternating quantity
 - (B) graph representing the frequency and phase of an amplifier
 - (C) an instrument used for determination phase difference between two time varying quantities
 - (D) a colour tag for distinguishing between different phases of 3-phase supply
- 47. When the output flows for less than one-half cycle of the input signal, the amplifier is said to operate in :
 - (A) Class-A mode
 - (B) Class-AB mode
 - (C) Class-B mode
 - (D) Class-C mode

| 48. | If an amplifier has an overall current gain of 200 and input resistance of | | | | | | |
|-------------|---|--|--|--|--|--|--|
| | 20 $k\Omega$ with a load resistance of 10 $k\Omega$. The overall voltage gain of the | | | | | | |
| | amplifier is: | | | | | | |
| | (A) 20 dB | | | | | | |
| | (B) 40 dB | | | | | | |
| | (C) 60 dB | | | | | | |
| | (D) 80 dB | | | | | | |
| 49. | Two amplifiers having mid band voltage gains 20 dB and 40 dB are connected | | | | | | |
| | in cascade. The overall voltage gain of the cascade configuration | | | | | | |
| | will be: | | | | | | |
| | (A) 800 dB | | | | | | |
| | (B) 60 dB | | | | | | |
| | (C) 30 dB | | | | | | |
| | (D) 2 dB | | | | | | |
| 50. | A class-B push-pull amplifier suffers from: | | | | | | |
| | (A) intermodulation distortion | | | | | | |
| | (B) excess harmonic distortion | | | | | | |
| | (C) cross-over distortion | | | | | | |
| | (D) none of the above | | | | | | |
| 51 . | An amplifier with a voltage gain of 1000 uses 1/100th of its output in negative | | | | | | |
| | feedback, the gain with feedback is: | | | | | | |
| | (A) 90.9 | | | | | | |
| | (B) 80.9 | | | | | | |

(C)

(D)

20.9

10.9

| 52 . | A pro | ogram that accepts a high-level language program as input and generates | |
|-------------|------------|---|-----|
| | a co | rresponding machine language program as output is called : | |
| | (A) | Linker | |
| | (B) | Loader | |
| | (C) | Compiler | |
| | (D) | Editor | |
| 53. | Out | of the following bridges which one is used for determination the | |
| | capa | citance: | |
| | (A) | Schering bridge | |
| | (B) | Wheatstone bridge | |
| | (C) | Kelvin bridge | |
| | (D) | Hay bridge | |
| 54. | Whi | ch one of the following operators does not belong to unary operator | 400 |
| 80 | grou | p ? | |
| | (A) | ++ | |
| | (B) | <= | |
| | (C) | | |
| | (D) | size of | |
| 55 . | Iden | tify the false statement from the following: | |
| | (A) | an integer quantity cannot be added to or subtracted from a pointer | |
| | | variable | |
| | (B) | a pointer variable can be assigned the address of an ordinary | 7 |
| | | variable | |
| | (C) | a pointer variable can be assigned the value of another pointer | |
| | | variable | |
| | (D) | a pointer variable can be assigned a null (zero) value | |
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| | | | |

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- 56. If i = 1, then on execution of ++ i statement the value of i will be:
 - (A) 1
 - (B) 2
 - (C) 3
 - (D) 4
- 57. Identify false statement. In C programming:
 - (A) a process directive may appear at any place in a source file
 - (B) only one processor directive can occur in a line
 - (C) a processor directive is terminated by a semicolon
 - (D) all processor directives begin with the sharp sign (#)
- 58. In C programming when working with stream-oriented data file, one has to establish first a buffer area. This is accomplished by:
 - (A) fwrite
 - (B) fopen
 - (C) fclose
 - (D) FILE
- 59. Which of the following operators enjoys the highest precedence in C programming?
 - (A) Unary operators
 - (B) Logical operators
 - (C) Relational operators
 - (D) Arithmetic operators
- 60. Idetnify the false statement from the following:
 - (A) A Union contains members whose individual data types may differ from one another
 - (B) The members that compose a union each are assigned its unique storage area within the computer's memory
 - (C) The members that compose a union all share the same storage area within the computer's memory
 - (D) A union can be member of a structure and a structure can be a member of a union.